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Applicant: Jeffrey D. Walker
Serial No.: 10/017,358
Filing Date: December 13, 2001
For: OPTICAL TRANSMITTER INCLUDING A LINEAR SEMICONDUCTOR OPTICAL AMPLIFIER

Confirmation No.: 6851
Att'y Docket No.: 15436.247.45.1.1
Group: 2633

References Cited by Applicants

While the filing of Information Disclosure Statements is voluntary, the procedure is governed by the guidelines of Section 609 of the Manual of Patent Examining Procedure and 37 C.F.R. §§ 1.97 and 1.98. To be considered a proper Information Disclosure Statement, Form PTO-1449 shall be accompanied by a copy of each listed patent or publication or other item of information and a translation of the pertinent portions of foreign documents (if an existing translation is readily available to the applicant), an explanation of relevance of each reference not in the English language, and should be submitted in a timely manner as set out in MPEP Sec. 609.

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Each citation initialed by the Examiner will be printed on the issued patent in the same manner as references cited by the Examiner on Form PTO-892.

The reference designations "A1," "A2," etc. (referring to Applicant's reference 1, Applicant's reference 2, etc.) will be used by the Examiner in the same manner as Examiner's reference designations "A," "B," "C," etc. on Office Action Form PTO-1142.

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INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Attorney's Docket No.	Serial No.
21153-05929	10/017,358
Applicant	
Jeffrey D. Walker	
Filing Date	**Group Art Unit**
December 13, 2001	2633

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REV: 02/01

FORM PTO-1449 (REV. 6-89) U.S. DEPARTMENT OF COMMERCE Patent and Trademark Office	Attorney's Docket No. 21153-05929	Serial No. 10/017,358
INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)	Applicant: Jeffrey D. Walker	
	Filing Date: December 13, 2001	Group Art Unit: Not yet known

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INFORMATION DISCLOSURE CITATION

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Attorney's Docket No.	Serial No.
21153-05929	10/017,358
Applicant	
Jeffrey D. Walker	
Filing Date	**Group Art Unit**
December 13, 2001	Not yet known

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D. Pepper	3/4/05

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